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DIODES, POWER RECTIFIER, SCHOTTKY BARRIER

BASED ON TYPE: STPS16MS

ESCC Detail Specification No. ST06/017

Issue 1

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Administrative/General Notes

(Refer to specifications for ESCC 0000 series)

Item No.	General Description
101	Administrative/General Notes/Specified ESCC



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5. GENERAL

5.1 SCOPE

This specification details the ratings, physical and chemical characteristics and test and inspection data for the component type variants within the range of components specified below. It supplements the requirements of associated test result in conjunction with the ESCC General Specification (not under duplicate documents).

5.2 APPLICABLE DOCUMENTS

The following documents form part of the specification and shall be read in conjunction with it:

- a) ESCC General Specification No. 0000
- b) MIL-STD-1312 Test Methods and Procedures for Semiconductor Devices

5.3 SYMBOLS, ABBREVIATIONS, DIMENSIONS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESCC Seal Specifications No. 010001 shall apply.

5.4 THE ESCC COMPONENT NUMBERING AND COMPONENT IDENTIFICATION

5.4.1 The ESCC Component Number

The ESCC Component Number shall be constructed as follows:

Example: 010017/01

- e – Seal Specification Reference: 010017
- e – Component Type Variant Number (if applicable)

5.4.2 Component Test Values

The component type variants applications this specification are as follows:

Variant Number	Material type	Case	Description	Minimum Electrical and Physical	Weight (max/g)
01	ESPC1001	ESCC1	Single stud	Q14	2
02	ESPC1001	ESCC1	Stud studs, common cathode	Q14	2

The terminal material and finish shall be in accordance with the requirements of ESCC Seal Specification No. 010001.

5.5 MAXIMUM RATINGS

The maximum ratings shall not be exceeded at any time during use or storage.

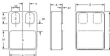
Maximum ratings apply only for a transient during testing by the system specified in this specification and when approved in Test Methods and Procedures within ESCC General Specifications.



Characteristics	Symbol	Maximum Ratings	Unit	Remarks
Forward Voltage (at I_{F0} per diode)	V_{F0}	200	V	Note 1
Repetitive Peak Reverse Voltage	V_{RRM}	65	V	Note 2
Surge Peak Reverse Voltage	V_{SRM}	7	V	Note 3
Average Rectified Current (per diode)	I_{A}		A	Note 4, 5, 7
Currents (in μ A) (per Diode) Voltage (V) per Diode		10 20		
Peak Forward Current (per Diode)	I_{FPM}	15	A	
Operating Temperature Range (Case Temperature)	T_{OP}	-55 to +175	°C	
Storage Temperature	T_{STG}	-55 to +175	°C	
Storage Temperature Range	T_{STGR}	-55 to +175	°C	
Working Temperature	T_{WJ}	200	°C	Note 6
Critical Rate of Rise of Reverse Voltage	dV/dt	1000	V/ μ s	
Forward Recovery, Junction Case Current (A) (per Diode) Voltage (V) per Diode	t_{rr}	400 1.0	μ s	Note 8, 7

NOTES:

1. Measured pulse at time t_{rr} .
2. Pulse duration time, $t \leq 10\mu$ s.
3. Pulse duration time, $t \leq 10\mu$ s.
4. For currents (in μ A) (per Diode) at $T_{OP} = +175^\circ\text{C}$, or Voltage (V) per Diode at $T_{OP} = +175^\circ\text{C}$, derive linearly to 0 at -55°C .
5. Exceeds 0 exceeds maximum and the same package shall not be used without careful thermal mass support.
6. Package mounted on infinite thermal mass.
7. For current (A) (per Diode) ratings apply only when both anode-cathodes tied together.

**4.2 Functional Description and Electrical Characteristics****4.2.1 Substrate Package (SMD) - 4 Terminal**

Symbol	Dimension mm		Notes
	Min	Max	
a	2.00	2.50	
b	2.00	2.50	
c	1.75	2.00	
d	0.50	0.50	
e	2.00	2.50	1
f	2.00	2.50	1
g	0.20	0.20	
h	0.20	-	1
i	1.00	1.50	
j	1.00	1.50	
k	1.25 (ESCC)		1

NOTES:

1. The terminal identification is specified by the component's geometry. See Functional Diagram for the terminal connections.
2. Options.

4.2 Functional Diagram**Symbol(s)**Terminal 1 and 2 are inputs
Terminal 3, 4 are outputs

Terminal 22

Terminal 19: Anode (+)
Terminal 20: Cathode (-)
Terminal 21: Common Cathode



NOTES

1. Terminal is not connected to any terminal.

2.6 TESTING & END PRODUCTS

Mounting and finishing shall be as follows:

- Case**
The case shall be hermetically sealed and house ceramic body with a Glass lid.
- Terminals**
As specified in Component Type Variants.

3. REQUIREMENTS

3.1 GENERAL

The complete requirements for procurement of the components specified herein are as stated in this specification and the ESCC Generic Specification. Permitted deviations from the Generic Specification, applicable to this specification only, are listed below.

Permitted deviations from the Generic Specification and this Serial Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESCC requirement and do not affect the component's reliability, are listed in the appendices attached to this specification.

3.1.1 Deviations from the Generic Specification

3.1.1.1 Deviations from Screening Tests – (Class F)

- High Temperature Reverse Bias Form-In and the subsequent Final Measurements for HTRB shall be waived.

3.1.1.2 Deviations from Qualification and Periodic Tests – (Class F)

- Complete Acceleration is not applicable.
- Terminal Strength is not applicable.

**2.2 Marking**

The marking shall be in accordance with the requirements of ESCC Seal Specification No. 020007 and as follows:

The information to be marked on the component shall be:

- Trade/ESCC qualified components symbol (for ESCC qualified components only).
- Trade/ESCC Component Number.
- Traceability information.

2.3 Performance and Reliability of Service Operations and Storage of Parts

Electrical measurements shall be performed at room, high and low temperatures. Conditions of use are given after the name.

2.3.1 Room Temperature Electrical Measurements

The measurements shall be performed at $T_{amb} = 23 \pm 0.5^\circ\text{C}$.

Parameter	Symbol	Meas. and Test Method	Test conditions: Note 1	Units		Units
				Min.	Max.	
Reverse Current	I_R	MB 6	DC Method $V_R = 50\text{V}$	-	mA	µA
Forward Voltage	V_{f1}	MB 1	Pulse Method pMB, Note 2	-	V	V
	V_{f2}	MB 1	Pulse Method pMB, Note 2	-	V	V
	V_{f3}	MB 1	Pulse Method pMB, Note 2	-	V	V
Capacitance	C_j	MB 7	$V_R = 0\text{V}$ AC Method	-	nF	pF
Storage Temperature, Junction or Case	$T_{stj,sc}$	MB 8	$I_F = 0\text{A}$ to I_{RM} , $I_R = 0\text{mA}$, $T_{amb} = 25^\circ\text{C}$, $T_{stj} = 150^\circ\text{C}$, Note 3	(Calculated θ_{stj} , see Note 4)		$^\circ\text{C}/\text{W}$

2.3.2 High and Low Temperature Electrical Measurements

Parameter	Symbol	Meas. and Test Method	Test conditions: Note 1 and 5	Units		Units
				Min.	Max.	
Reverse Current	I_R	MB 6	$T_{amb} = 100^\circ\text{C}$ to 150°C , DC Method $V_R = 50\text{V}$	-	mA	µA



Characteristics	Symbols	Type, Size, and Test Method	Test Conditions (Notes 1 and 2)	Limits		Units
				Min ¹	Max ²	
Forward Voltage	V_{f1}	100V	$I_{f1} = 100 \text{ mA}$ (2) 100% Pulse/Maximum $t_{p1} \leq 10 \mu\text{s}$, Note 3	-	100	V _{DC}
	V_{f2}	100V	$I_{f2} = 100 \text{ mA}$ (2) 100% Pulse/Maximum $t_{p2} \leq 10 \mu\text{s}$, Note 3	-	100	V _{DC}
	V_{f3}	100V	$I_{f3} = 100 \text{ mA}$ (2) 100% Pulse/Maximum $t_{p3} \leq 10 \mu\text{s}$, Note 3	-	100	V _{DC}
	V_{f4}	100V	$I_{f4} = 100 \text{ mA}$ (2) 100% Pulse/Maximum $t_{p4} \leq 10 \mu\text{s}$, Note 3	-	100	V _{DC}

4.3.3 Forward Voltage Measurement

- Measurements per each diode.
- Pulse width shall be less than 100 ns.
- Perform test only during forward bias. The greater ITR values (higher measurements) groups.
- The limits for I_{f1} shall be defined by the manufacturer unless set in accordance with the ITR. The interval of the statistical process shall be $t_{p1} \leq 10 \mu\text{s}$ (note specified in Maximum Rating).
- Repeat and record measurements. Start the performance a sample of 5 components with 10 values. Interactivity = 100%. Inspection may be performed.

4.4 Reverse Current (MUTUAL)

Unless otherwise specified, the measurements shall be performed at $T_{amb} = 100 \pm 0.5^\circ\text{C}$.

The test methods and test conditions shall be as per the corresponding test defined in: Heat Temperature Electrical Measurements.

The tolerances (σ) shall not be provided for each characteristic specified. The corresponding absolute tolerances for each characteristic shall not be assessed.

Characteristics	Symbols	Limits			Units
		Min Value σ	Max		
			Min ¹	Max ²	
Reverse Current	I_{r1}	100 μA (2) ± 10%	-	100	μA
Forward Voltage	V_{f1}	100	-	100	V _{DC}
	V_{f2}	100	-	100	V _{DC}

NOTES:

- Interchange is the greater referred to the total value.

**2.5. OPERATIONAL AND END-POINT ELECTRICAL CHARACTERISTICS**

Unless otherwise specified, the measurements shall be performed at $T_{amb} = 25 \pm 0.5$ °C.

The test methods and test conditions shall be as per the corresponding test defined in IEC60747-15:2006 Electrical Measurements.

The instructions for each characteristic shall not be exceeded.

Characteristic	Symbol	Limits		Units
		Min	Max	
Forward current	I_F	-	100	µA
Reverse voltage	V_{RM}	-	1000	V _{DC}
	V_{RM}	-	100	V _{DC}
	V_{RM}	-	1000	V _{DC}

2.6. ELECTRICAL CONDITIONS

Characteristic	Symbol	Test condition	Units
Case temperature	T_{case}	25°C	°C
Reverse voltage	V_R	0V	V

2.7. OTHER TESTS AND CONDITIONS

The manufacturer has to specify the Power Factor.



APPENDIX

GENERAL CONDITIONS FOR PURCHASE CONTRACTS

ITEM NUMBER	DESCRIPTION OF CONDITIONS
Conditions for Production - General - Class F1	General EC Production - General - Budgets and equipment. Trade discounts are acceptable for handling with a minimum cost.
Conditions for Selling Terms - Class F1	Contracting a comprehensive sales agreement. Agreement to sell - General Sales.